## NSN 5962-01-306-5557

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View Online at https://aerobasegroup.com/nsn/5962-01-306-5557

Overall Langths
Overall Length:
1.490 inches
Overall Height: 0.432 inches
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Overall Width:
0.620 inches
Body Length:
1.490 inches
Body Width:
0.610 inches
Body Height:
0.107 inches
Maximum Power Dissipation Rating:
1.155 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Bipolar and burn in and monolithic
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
19 input
Case Outline Source And Designator:
D-10 mil-m-38510
Current Rating Per Characteristic:
30.00 milliamperes forward current, nonrepetitive, peak total value absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
7.0 volts power source
Memory Device Type:
Ram
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:

28 printed circuit

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Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

Fiig:

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